TLP665J(S)

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TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

TLP665J(S)

OFFICE MACHINE HOUSEHOLD USE EQUIPMENT TRIAC DRIVERSOLID STATE RELAY

TOSHIBA TLP665J(S) consists of a photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

: 600V(Min)

: 10mA(Max)

: 100mA(Max)

: 5000Vrms(Min)

: DIN VDE0884

: 890Vрк

:8000 VPK

: UL1577, File No.E67349

: SS EN60065, File No.9841102

SS EN60950, File No.9841102

: BS EN60065, File No.8385

BS EN60950, File No.8386

Certificate No.101399

- Peak Off-State Voltage
- Trigger LED Current
- On-State Current
- Isolation Voltage
- UL Recognized
- SEMKO Approved
- BSI Approved
- Option(D4)type VDE Approved

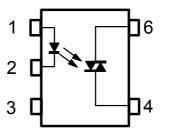
Maximum Operating Insulation Voltage Highest Permissible Over Voltage

(Note)When a VDE0884 approved type is needed, please designate the "Option(D4)"

Construction Mechanical Rating

	7.62 mm pich standard type	10.16 mm pich TLPXXXF type
Creepage Distance	7.0 mm (Min)	8.0 mm (Min)
Clearance	7.0 mm (Min)	8.0 mm (Min)
Insulation Thickness	0.5 mm (Min)	0.5 mm (Min)

PIN CONFIGURATION (TOP VIEW)



1: ANODE 2: CATHODE 3: N.C. 4:TERMINAL1 6:TERMINAL2

単位: mm

7.62 ± 0.25

0.25 -0.0

7.85~8.80

6.4 ± 0.25

3.65 -0.15

0.15 NIN S N 0.8 ± 0.25

11-7A9

7.12 ± 0.25

2.54 ± 0.25

 $0.5 \pm 0.$

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Weight: 0.39 g

MAXIMUM RATINGS(Ta=25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT		
	Forward Current	l _F	50	mA		
Ω	□ Forward Current Derating (Ta≥53°C)			-0.7	mA /°C	
Щ	Peak Forward Current (100µs pulse, 100pps)			1	А	
	Reverse Voltage			5	V	
	Off-State Output Terminal Voltage	V_{DRM}	600	V		
	On-State RMS Current	Ta=25°C	I _{T(RMS)}	100	mA	
RO		Ta=70°C	I (RMS)	50		
DETECTOR	On-State Current Derating (Ta≥25°C)	∆I _T /°C	-1.1	mA /°C		
DEJ	Peak On-State Current (100µs pulse, 120pps)	I _{TP}	2	А		
	Peak Nonrepetitive Surge Current (Pw=10ms,DC=10	I _{TSM}	1.2	А		
	Junction Temperature	Тj	115	°C		
Ope	erating Temperature Range	T _{opr}	-40~100	°C		
Stor	age Temperature Range	T _{stg} −55~125		°C		
Lea	d Soldering Temperature (10s)	T _{sol}	260	°C		
Isola	ation Voltage (AC,1min. , R.H.≤60%)	BVS	5000	Vrms		

(Note 2)Pins1,2 and 3 shorted together and pin4 and pin6 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{AC}	—	—	240	V _{ac}
Forward Current	I _F	15	20	25	mA
Peak On-State Current	I _{TP}	_	_	1	А
Operating Temperature	T _{opr}	-25		85	°C

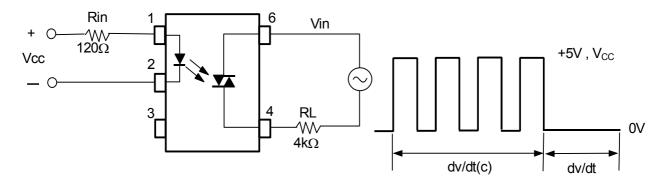
ELECTRICAL CHARACTERISTICS(Ta=25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I _R	V _R = 5 V		_	10	μA
	Capacitance	Ст	V = 0, f=1MHz		30	_	pF
Ц	Peak Off-State Current	I _{DRM}	V _{DRM} =600V		10	1000	nA
0	Peak On-State Voltage	V _{TM}	I _{TM} =100mA		1.7	3.0	V
U	Holding Current	Ι _Η	—		1.0	—	mA
Ц Ц	Critical Rate of Rise of Off-State Voltage	dv/dt	Vin=240Vrms , Ta=85°C (Note3)	—	500	_	V/µs
DE	Critical Rate of Rise of Commutating Voltage	dv/dt(c)	Vin=60Vrms , IT=15mA (Note3)	—	0.2	_	V/µs

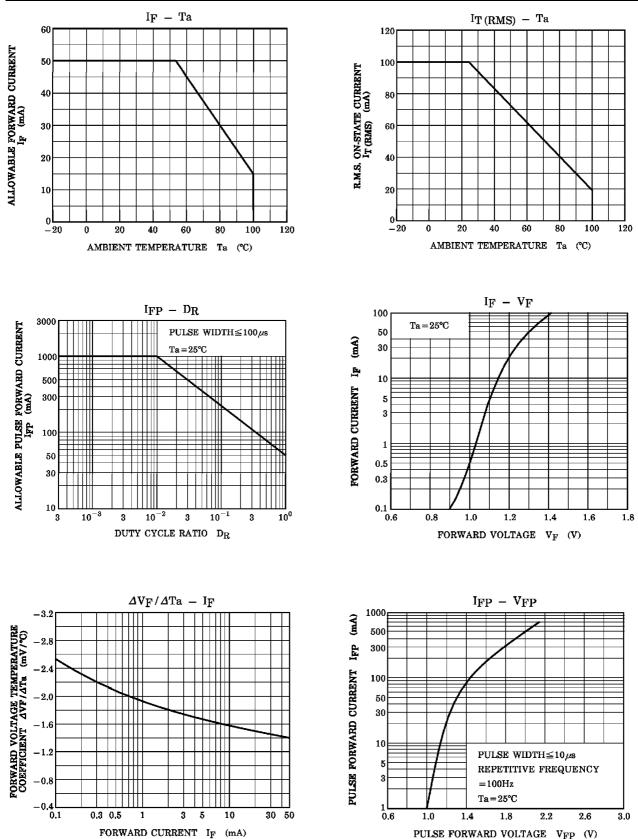
COUPLED ELECTRICAL CHARACTERISTICS(Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I _{FT}	V _T =6V	—	5	10	mA
Capacitance (Input to Output)	Cs	VS=0 , f=1MHz	—	0.8	_	pF
Isolation Resistance	Rs	VS=500V	1×10 ¹²	10 ¹⁴	_	Ω
Isolation Voltage	BVs	AC , 1minute	5000	_	_	Vrms
		AC, 1second,in oil	—	10000	_	VIIIS
		DC , 1minute,in oil	_	10000	_	Vdc

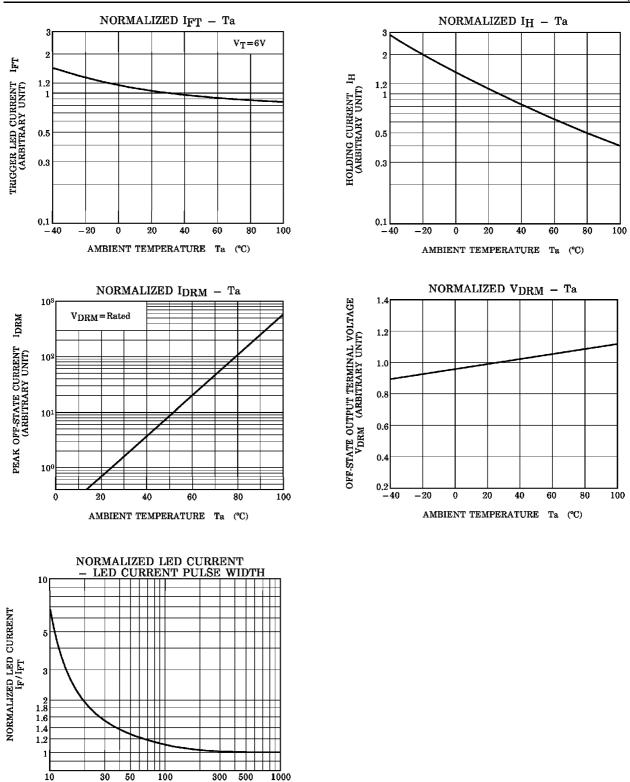
(Note 3)dv/dt TEST CIRCUIT



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LED CURRENT PULSE WIDTH P_W (μ s)

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